

# isc N-Channel MOSFET Transistor

### **FEATURES**

- Drain Current –I<sub>D</sub>=32A@ T<sub>C</sub>=25 °C
- Drain Source Voltage-
  - : V<sub>DSS</sub>=100V(Min)
- Static Drain-Source On-Resistance
  - :  $R_{DS(on)} = 37m \Omega (Max)$
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### **DESCRIPTION**

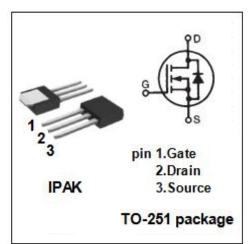
 Designed for use in switch mode power supplies and general purpose applications.

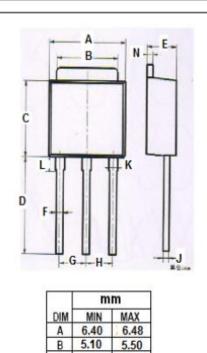
# ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	100	V
V <sub>GS</sub>	Gate-Source Voltage-Continuous	±20	V
I <sub>D</sub>	Drain Current-Continuous	32	А
I <sub>DM</sub>	Drain Current-Single Pluse	70	А
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	100	W
TJ	Max. Operating Junction Temperature	-55~175	°C
T <sub>stg</sub>	Storage Temperature	-55~175	$^{\circ}$

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	1.5	°C/W





	mm	
DIM	MIN	MAX
Α	6.40	6.48
В	5.10	5.50
C	5.80	6.20
D	9.20	9.60
E	2.20	2.40
F	0.50	0.70
G	2.09	2.49
Н	2.09	2.49
J	0.40	0.60
K	0.70	0.90
L	1.60	2.00
N	0.40	0.60



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**AOI482** 

### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
V <sub>(BR)DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0; I <sub>D</sub> = 0.25mA	100		V
V <sub>GS(th)</sub>	Gate Threshold Voltage V <sub>DS</sub> = 5V; I <sub>D</sub> = 0.25mA		1.6	2.7	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> = 10V; I <sub>D</sub> =10A		37	mΩ
Igss	Gate-Body Leakage Current	V <sub>GS</sub> = ±20V;V <sub>DS</sub> = 0		±100	nA
I <sub>DSS</sub>	Zero Gate Voltage Drain Current	V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0 V <sub>DS</sub> = 100V; V <sub>GS</sub> = 0@T <sub>J</sub> = 55°C		1 5	μА
V <sub>SD</sub>	Forward On-Voltage	I <sub>S</sub> = 1A; V <sub>GS</sub> = 0		1	V

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